



N-CHANNEL ENHANCEMENT MODE MOSFET

Features

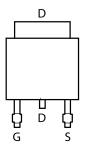
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

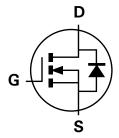
- Case: TO252-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram
- Terminals: Matte Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.33 grams (approximate)







PIN OUT -TOP VIEW



Equivalent Circuit

Ordering Information (Note 3)

| Part Number | Case | Packaging |
|---------------|----------|--------------------|
| DMN3005LK3-13 | TO252-3L | 2500 / Tape & Reel |

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com.
- 3. For packaging details, go to our website at http://www.diodes.com.

Marking Information



DII = Manufacturer's Marking
N3005L = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 09 = 2009)
WW = Week (01 - 53)

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Maximum Ratings @T_A = 25°C unless otherwise specified

| Characteristic | | | Symbol | Value | Unit |
|---|-----------------|--|------------------|--------------|------|
| Drain-Source Voltage | | | V_{DSS} | 30 | V |
| Gate-Source Voltage | | | V _{GSS} | ±20 | V |
| Continuous Drain Current (Note 4) V _{GS} = 10V | Steady State | T _A = 25°C T _A = 85°C | I _D | 14.5 10.5 | А |
| Continuous Drain Current (Note 5) V _{GS} = 10V | Steady State | T _A = 25°C T _A = 85°C | I _D | 22 16 | А |
| Pulsed Drain Current (Note 6) | | | I _{DM} | 48 | Α |

Thermal Characteristics

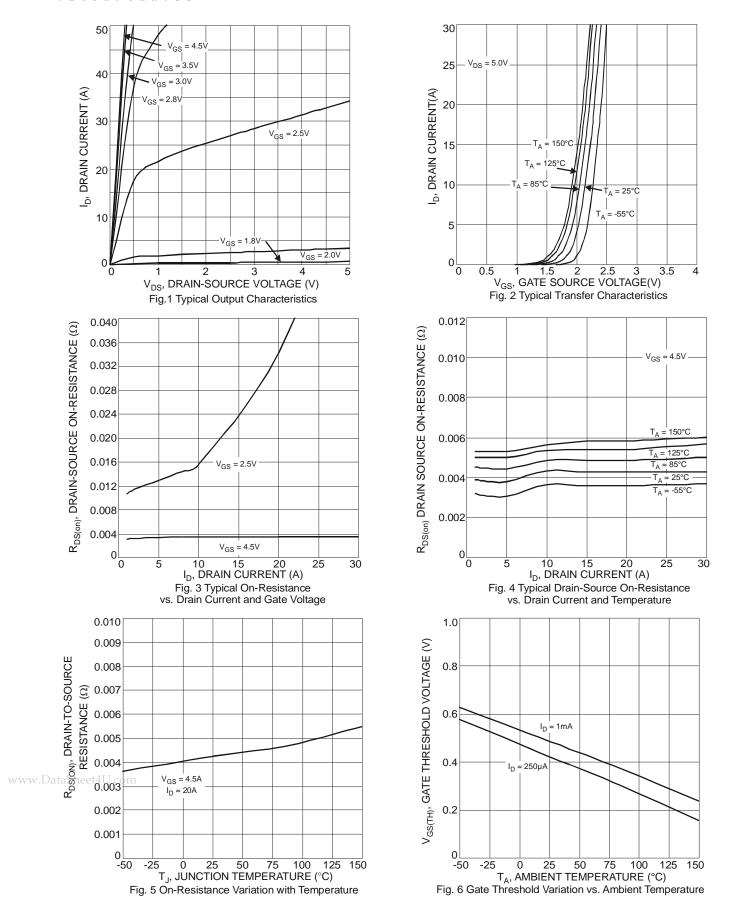
| Characteristic | Symbol | Value | Unit |
|---|------------------|-------------|------|
| Power Dissipation (Note 4) | P _D | 1.68 | W |
| Thermal Resistance, Junction to Ambient @T _A = 25°C (Note 4) | $R_{\theta JA}$ | 74.3 | °C/W |
| Power Dissipation (Note 5) | P _D | 4.1 | W |
| Thermal Resistance, Junction to Ambient @T _A = 25°C (Note 5) | R _{θJA} | 30.8 | °C/W |
| Operating and Storage Temperature Range | T_{J}, T_{STG} | -55 to +150 | °C |

Electrical Characteristics @T_A = 25°C unless otherwise specified

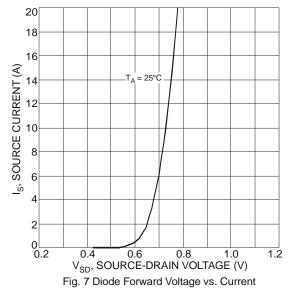
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|---|----------------------|-----|------|------|------|---|--|
| OFF CHARACTERISTICS (Note 7) | 1 07 | | - 71 | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 30 | - | - | V | $V_{GS} = 0V, I_D = 250\mu A$ | |
| Zero Gate Voltage Drain Current T _J = 25°C | I _{DSS} | - | - | 1.0 | μA | $V_{DS} = 30V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | - | - | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | 1.0 | 1.5 | 2.0 | V | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | |
| Statia Drain Sauras On Besistanes | D | | 3.6 | 5.0 | m0 | $V_{GS} = 10V, I_D = 20A$ | |
| Static Drain-Source On-Resistance | R _{DS} (ON) | - | 4.9 | 6.5 | mΩ | $V_{GS} = 4.5V, I_D = 20A$ | |
| Forward Transfer Admittance | Y _{fs} | - | 22 | - | S | $V_{DS} = 15V, I_D = 15A$ | |
| Diode Forward Voltage | V_{SD} | - | 8.0 | 1.0 | V | $V_{GS} = 0V, I_{S} = 20A$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | C _{iss} | - | 4342 | - | pF | 45)/)/ | |
| Output Capacitance | Coss | - | 1801 | - | pF | $V_{DS} = 15V, V_{GS} = 0V,$ f = 1.0MHz | |
| Reverse Transfer Capacitance | C_{rss} | - | 669 | - | pF | T = 1.0WITZ | |
| Gate Resistance | Rg | - | 1.76 | - | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$ | |
| Total Gate Charge | Qg | - | 46.9 | - | nC | | |
| Gate-Source Charge | Q_{gs} | - | 14.3 | - | nC | $V_{GS} = 4.5V, V_{DS} = 15V,$ | |
| Gate-Drain Charge | Q_gd | - | 18.6 | - | nC | $I_D = 15A$ | |
| Turn-On Delay Time | t _{D(on)} | - | 7.9 | - | ns | | |
| Turn-On Rise Time | t _r | - | 22.8 | - | ns | V _{DS} = 15V, V _{GS} = 10V, | |
| Turn-Off Delay Time | t _{D(off)} | - | 73.4 | - | ns | $R_L = 1.3\Omega R_G = 3\Omega$ | |
| Turn-Off Fall Time | t _f | - | 43.5 | - | ns | | |

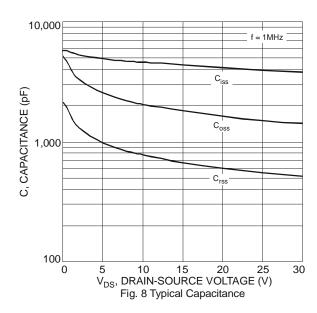
- 4. Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided.
- 5. Device mounted on 2" x 2" FR-4 PCB with high coverage 2oz. copper, single sided.
- 6. Repetitive rating, pulse width limited by junction temperature and current limited by package.
 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.

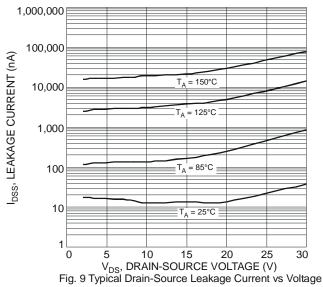


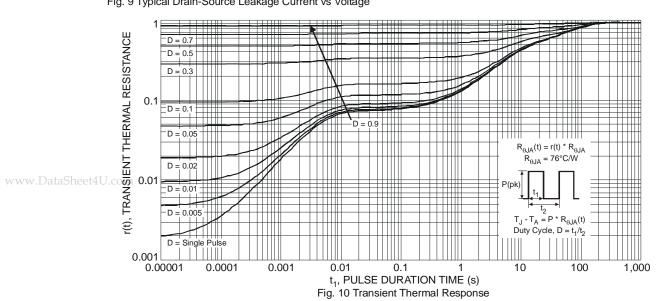






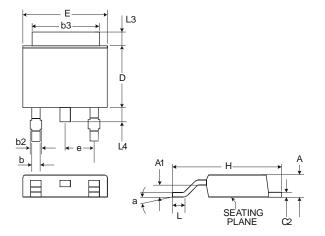






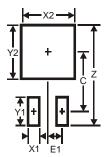


Package Outline Dimensions



| TO252-3L | | | | | |
|----------------------|------------|------|-------|--|--|
| Dim | Min | Тур | Max | | |
| Α | 2.19 | 2.29 | 2.39 | | |
| A1 | 0.97 | 1.07 | 1.17 | | |
| b | 0.64 | 0.76 | 0.88 | | |
| b2 | 0.76 | 0.95 | 1.14 | | |
| b3 | 5.21 | 5.33 | 5.50 | | |
| C2 | 0.45 | 0.51 | 0.58 | | |
| D | 6.00 | 6.10 | 6.20 | | |
| Е | 6.45 | 6.58 | 6.70 | | |
| е | 2.286 Typ. | | | | |
| Н | 9.40 | 9.91 | 10.41 | | |
| L | 1.40 | 1.59 | 1.78 | | |
| L3 | 0.88 | 1.08 | 1.27 | | |
| L4 | 0.64 | 0.83 | 1.02 | | |
| а | 0° | - | 10° | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 11.6 |
| X1 | 1.5 |
| X2 | 7.0 |
| Y1 | 2.5 |
| Y2 | 7.0 |
| С | 6.9 |
| E1 | 2.3 |

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